

International
IOR Rectifier

HFA180NH40PbF

HEXFRED™

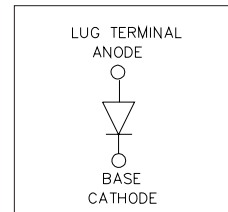
Ultrafast, Soft Recovery Diode

Features

- Very Low Qrr and trr
- Lead-Free

Benefits

- Reduced RFI and EMI
- Reduced Snubbing



Description/ Applications

HEXFRED™ diodes are optimized to reduce losses and EMI/ RFI in high frequency power conditioning systems. An extensive characterization of the recovery behavior for different values of current, temperature and di/dt simplifies the calculations of losses in the operating conditions. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.

Absolute Maximum Ratings

Parameters	Max	Units
V_R Cathode-to-Anode Voltage	400	V
$I_F @ T_C = 25^\circ\text{C}$ Continuous Forward Current	395	A
$I_F @ T_C = 100^\circ\text{C}$ Continuous Forward Current	200	
I_{FSM} Single Pulse Forward Current ①	1200	
E_{AS} Non-Repetitive Avalanche Energy ②	1.4	mJ
$P_D @ T_C = 25^\circ\text{C}$ Maximum Power Dissipation	657	W
$P_D @ T_C = 100^\circ\text{C}$ Maximum Power Dissipation	263	
T_J, T_{STG} Operating Junction and Storage Temperature Range	- 55 to 150	°C

Case Styles



HALF-PAK (D-67)

① Limited by junction temperature

② L = 100µH, duty cycle limited by max T_J

Electrical Characteristics (per Leg) @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
V_{BR} Cathode Anode Breakdown Voltage,	400	-	-	V	$I_R = 100\mu\text{A}$
V_{FM} Max. Forward Voltage	-	1.08	1.46	V	$I_F = 180\text{A}$
	-	1.22	1.8	V	$I_F = 360\text{A}$ See Fig. 1
	-	0.99	1.34	V	$I_F = 180\text{A}, T_J = 125^\circ\text{C}$
I_{RM} Max. Reverse Leakage Current	-	-	4	mA	$T_J = 125^\circ\text{C}, V_R = 400\text{V}$ See Fig. 2
C_T Junction Capacitance	-	370	500	pF	$V_R = 200\text{V}$ See Fig. 3
L_S Series Inductance	-	6.0	-	nH	From top of terminal hole to mounting plane

Dynamic Recovery Characteristics @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
t_{rr} Reverse Recovery Time	-	90	140	ns	$T_J = 25^\circ\text{C}$ See Fig. 5
	-	280	440		$T_J = 125^\circ\text{C}$
I_{RRM} Peak Recovery Current	-	9	16	A	$T_J = 25^\circ\text{C}$ See Fig. 6
	-	18	32		$T_J = 125^\circ\text{C}$
Q_{rr} Reverse Recovery Charge	-	300	950	nC	$T_J = 25^\circ\text{C}$ See Fig. 7
	-	2650	6300		$T_J = 125^\circ\text{C}$
$di_{(rec)M}/dt$	-	300	-	A/ μs	$T_J = 25^\circ\text{C}$ See Fig. 8
	-	290	-		$T_J = 125^\circ\text{C}$

$I_F = 135\text{A}$
 $V_R = 200\text{V}$
 $di_F/dt = 200\text{A}/\mu\text{s}$

Thermal-Mechanical Specifications

Parameters	Values	Units	Conditions	
T_J Max. Junction Temperature Range	-55 to 150	$^\circ\text{C}$		
T_{stg} Max. Storage Temperature Range	-55 to 150	$^\circ\text{C}$		
R_{thJC} Max. Thermal Resistance Junction to Case	0.19	$^\circ\text{C}/\text{W}$	DC operation * See Fig. 4	
R_{thCS} Typical Thermal Resistance, Case to Heatsink	0.05	$^\circ\text{C}/\text{W}$	Mounting surface, smooth and greased	
wt Approximate Weight	30(1.06)	g(oz.)		
T Mounting Torque	Min.	3(26.5)	Non-lubricated threads	
	Max.	4(35.4)		
	Terminal Torque	Min.		3.4(30)
		Max.		5(44.2)
Case Style	HALF PAK Module			

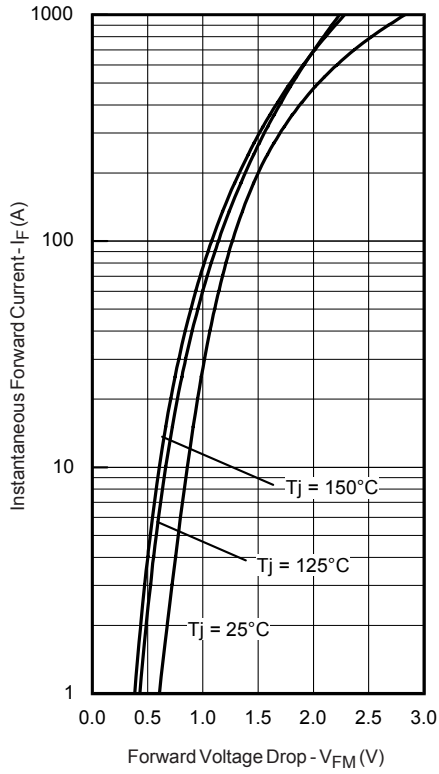


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current

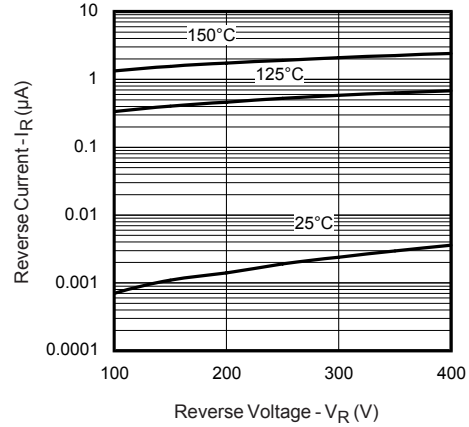


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

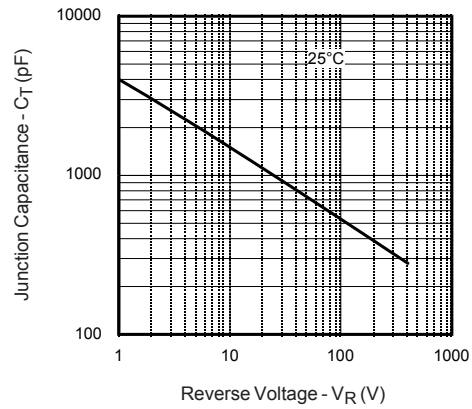


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

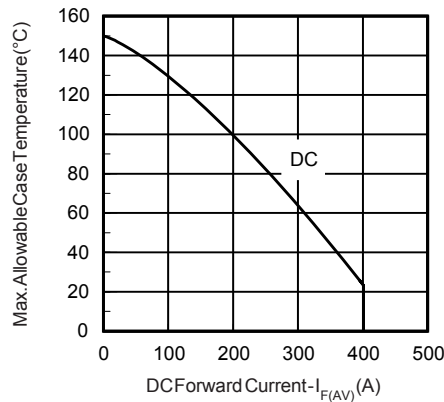


Fig. 4 - Max. Allowable Case Temperature Vs. DC Forward Current

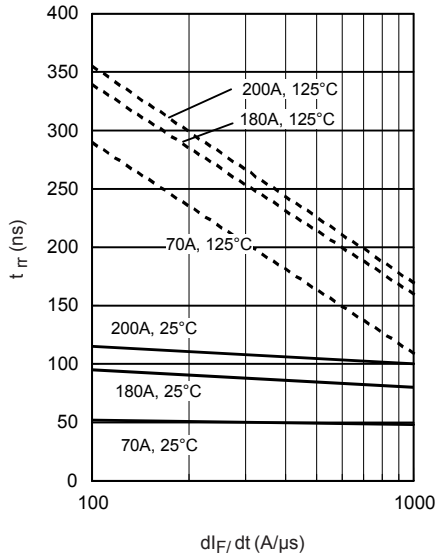


Fig. 5 - Typical Reverse Recovery vs. di_F/dt

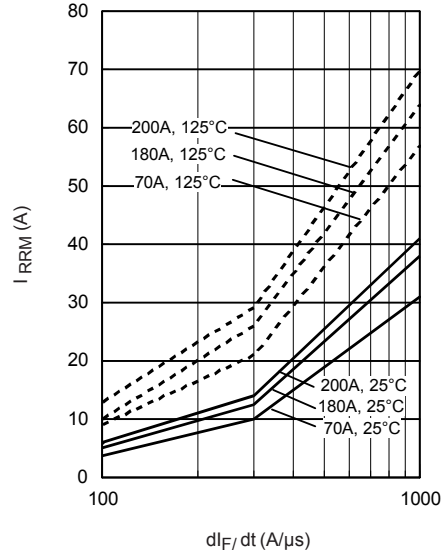


Fig. 6 - Typical Recovery Current vs. di_F/dt

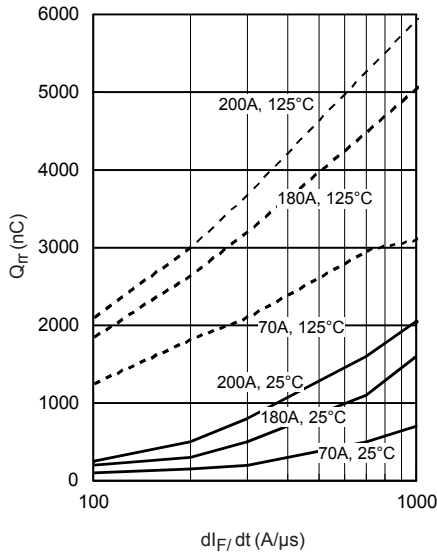


Fig. 7 - Typical Stored Charge vs. di_F/dt

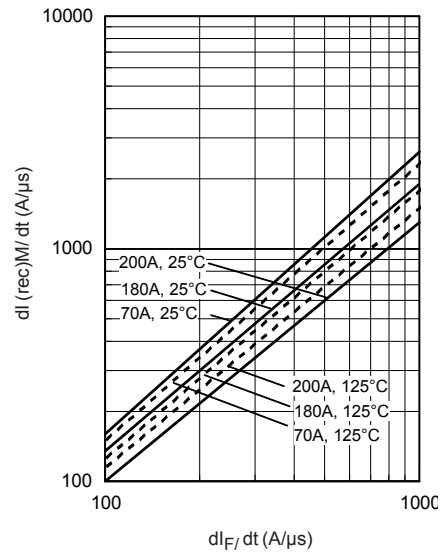


Fig. 8 - Typical $di_{(rec)M}/dt$ vs. di_F/dt

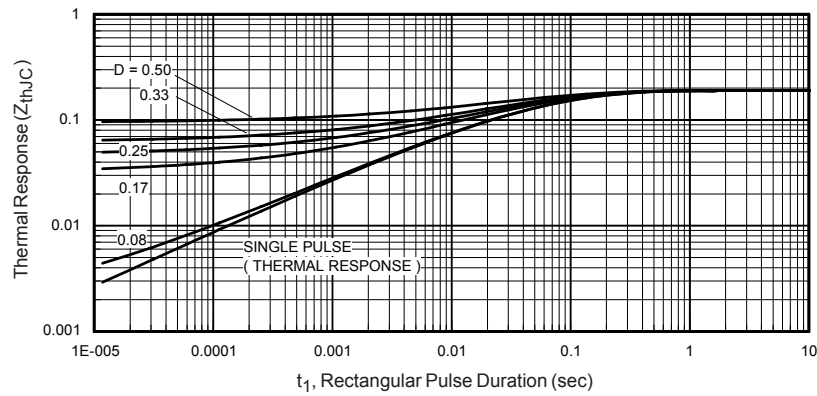


Fig. 9 - Maximum Thermal Impedance Z_{thJC} Characteristics

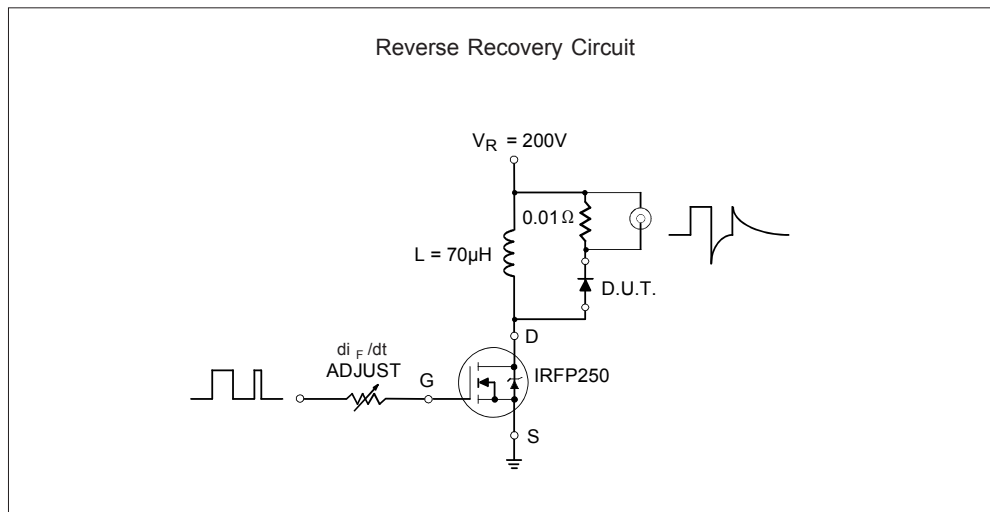


Fig. 10 - Reverse Recovery Parameter Test Circuit

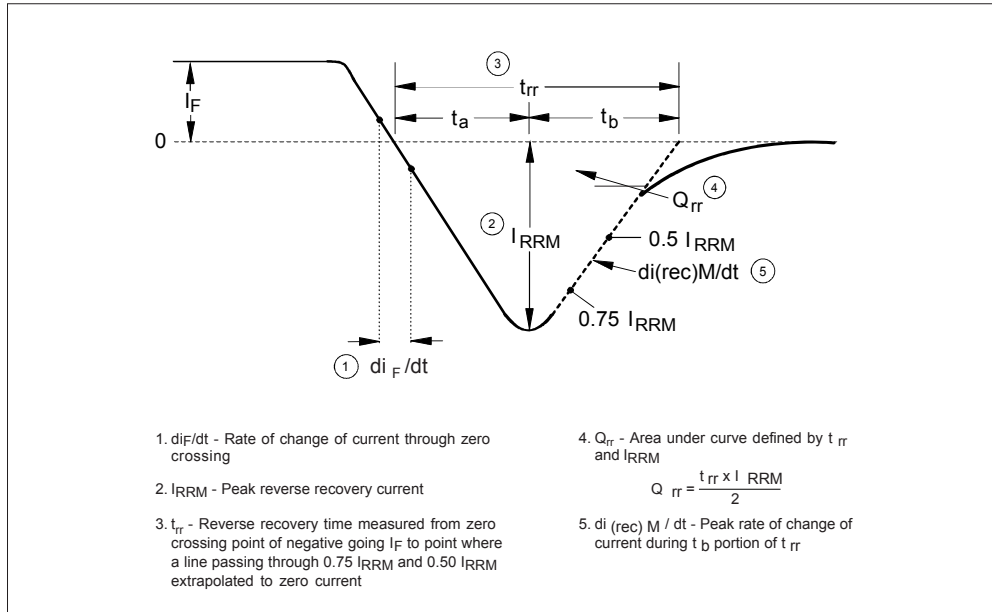


Fig. 11 - Reverse Recovery Waveform and Definitions

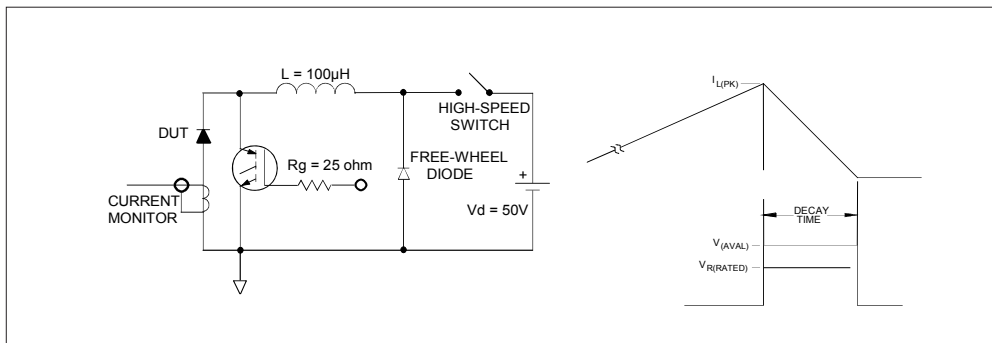
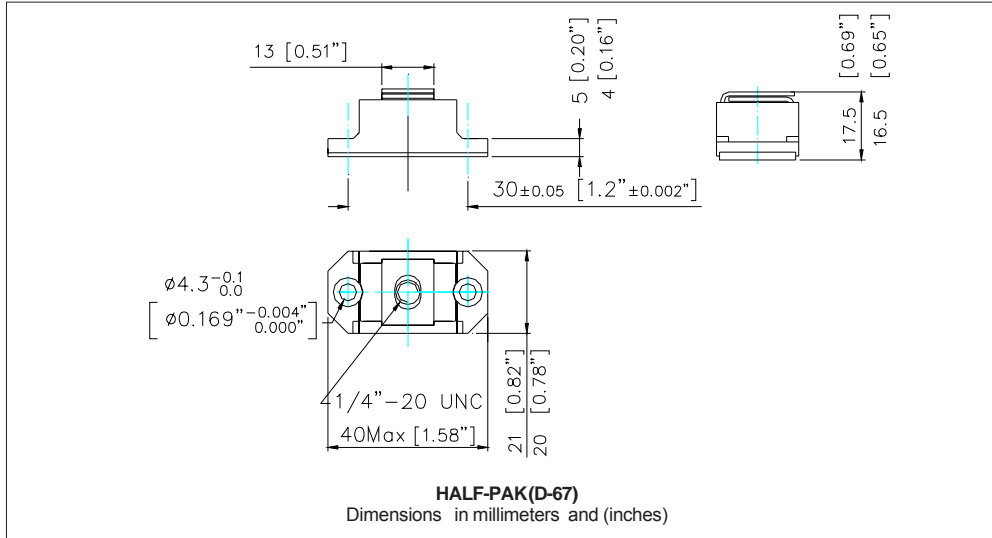


Fig. 12 - Avalanche Test Circuit and Waveforms

Outline Table



Ordering Information Table

Device Code					
HFA	180	N	H	40	PbF
1	2	3	4	5	6
1	2	3	4	5	6
1	2	3	4	5	6
1	2	3	4	5	6
1	2	3	4	5	6
1	2	3	4	5	6
1	2	3	4	5	6

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level and Lead-Free.
Qualification Standards can be found on IR's Web site.



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